

**REVISIONS**

LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Make change to input leakage current test, overvoltage protected test, positive supply current test, negative supply current test, and break-before-make time delay test as specified in table I herein. - ro	98-12-15	Raymond Monnin
B	Make changes to the descriptive designator under 1.2.4. Change ratings values under 1.3. Editorial changes throughout. -lgt	99-06-15	Raymond Monnin
C	Make changes to figure 3 timing diagrams. -rrp	00-06-29	Raymond Monnin
D	Update drawing to current requirements. Delete paragraphs 4.4.4.2 and 4.4.4.3. Editorial changes throughout. - drw	06-07-28	Raymond Monnin
E	Redrawn. Update paragraphs to MIL-PRF-38535 requirements. - drw	17-09-07	Charles F. Saffle

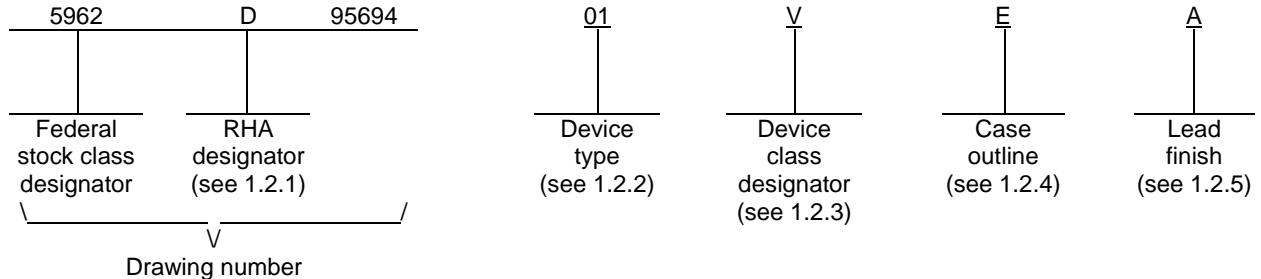


REV																				
SHEET																				
REV	E																			
SHEET	15																			
REV STATUS OF SHEETS	REV	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	
	SHEET	1	2	3	4	5	6	7	8	9	10	11	12	13	14					
PMIC N/A	PREPARED BY Sandra Rooney	<p align="center"><b>DLA LAND AND MARITIME</b>  <b>COLUMBUS, OHIO 43218-3990</b>  <a href="http://www.landandmaritime.dla.mil">http://www.landandmaritime.dla.mil</a></p>																		
<p align="center"><b>STANDARD MICROCIRCUIT DRAWING</b></p> <p>THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE</p> <p align="center">AMSC N/A</p>	CHECKED BY Sandra Rooney																			
	APPROVED BY Michael A. Frye	<p align="center">MICROCIRCUIT, LINEAR, RADIATION HARDENED CMOS, MULTIPLEXER / DEMULTIPLEXER WITH ACTIVE OVERVOLTAGE PROTECTION, MONOLITHIC SILICON</p>																		
	DRAWING APPROVAL DATE 96-02-27																			
	REVISION LEVEL E		<table border="1"> <tr> <td>SIZE A</td> <td>CAGE CODE <b>67268</b></td> <td><b>5962-95694</b></td> </tr> </table>	SIZE A	CAGE CODE <b>67268</b>	<b>5962-95694</b>														
SIZE A	CAGE CODE <b>67268</b>	<b>5962-95694</b>																		
		SHEET	1 OF 15																	

1. SCOPE

1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device class Q) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.

1.2 PIN. The PIN is as shown in the following example:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device types. The device types identify the circuit function as follows:

<u>Device type</u>	<u>Generic number</u>	<u>Circuit function</u>
01	HS548RH	Radiation hardened DI CMOS single 8-channel MUX / DEMUX with active overvoltage protection
02	HS549RH	Radiation hardened DI CMOS single 4-channel MUX / DEMUX with active overvoltage protection

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

<u>Device class</u>	<u>Device requirements documentation</u>
Q or V	Certification and qualification to MIL-PRF-38535

1.2.4 Case outline. The case outline is as designated in MIL-STD-1835 as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
E	GDIP1-T16 or CDIP2-T16	16	Dual-in-line

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V.

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1.3 Absolute maximum ratings. 1/

Supply voltage between +V and -V .....	+44 V
Supply voltage between +V and ground .....	+22 V
Supply voltage between -V and ground .....	-25 V
Digital input voltage range	
+V <sub>EN</sub> , +V <sub>A</sub> .....	+V <sub>SUPPLY</sub> + 4 V
-V <sub>EN</sub> , -V <sub>A</sub> .....	-V <sub>SUPPLY</sub> - 4 V
Analog input voltage range	
+V <sub>S</sub> .....	+V <sub>SUPPLY</sub> + 20 V
-V <sub>S</sub> .....	-V <sub>SUPPLY</sub> - 20 V
Peak current, S or D (pulsed at 1 ms, 10 percent duty cycle maximum) .....	40 mA
Storage temperature range .....	-65°C to +150°C
Maximum power dissipation at T <sub>A</sub> = +125°C (P <sub>D</sub> ) .....	0.63 W <u>2/</u>
Thermal resistance, junction-to-case (θ <sub>JC</sub> ) .....	24°C/W
Thermal resistance, junction-to-ambient (θ <sub>JA</sub> ) .....	80°C/W
Lead temperature (soldering, 10 seconds) .....	+300°C
Junction temperature (T <sub>J</sub> ) .....	+175°C

1.4 Recommended operating conditions.

Operating supply voltage (±V <sub>SUPPLY</sub> ) .....	±15 V
Analog input voltage (V <sub>S</sub> ) .....	±V <sub>SUPPLY</sub>
Logic low level (V <sub>AL</sub> ) .....	0 V to 0.8 V
Logic high level (V <sub>AH</sub> ) .....	+4 V to +V <sub>SUPPLY</sub>
Maximum RMS current, S or D .....	8 mA
Ambient operating temperature range (T <sub>A</sub> ) .....	-55°C to +125°C

1.5 Radiation features.

Maximum total dose available (dose rate = 50-300 rads (Si)/s).....	10 Krads (Si)
Latch-up <u>3/</u> .....	None

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.  
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

- 1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- 2/ If device power exceeds package dissipation capacity, provide heat sinking or derate linearly ( the derating is based on θ<sub>JA</sub>) at 12.5 mW/°C for case outline E.
- 3/ Guaranteed by process or design, not tested.

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DEPARTMENT OF DEFENSE HANDBOOKS

- MIL-HDBK-103 - List of Standard Microcircuit Drawings.
- MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <http://quicksearch.dla.mil> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 as specified herein, or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V.

3.2.1 Case outline. The case outline shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth tables. The truth tables shall be as specified on figure 2.

3.2.4 Radiation exposure circuit. The radiation exposure circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing and acquiring activity upon request.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 shall be provided with each lot of microcircuits delivered to this drawing.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T <sub>A</sub> ≤ +125°C -V = -15 V, +V = +15 V  V <sub>EN</sub> = 4.0 V unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Input leakage current <u>1/</u>	I <sub>IH</sub>	Measure inputs sequentially, connect all unused inputs to GND	1, 2, 3	01, 02	-1.0	1.0	μA
	I <sub>IL</sub>				-1.0	1.0	
	I <sub>IH</sub> , I <sub>IL</sub>		M, D <u>2/</u>	1		-1.0	
Leakage current into the source terminal of an "OFF" switch	+I <sub>S(OFF)</sub>	V <sub>S</sub> = +10 V, V <sub>EN</sub> = 0.8 V, all unused inputs = -10 V, V <sub>D</sub> = -10 V	1	01, 02	-10	+10	nA
			2, 3		-50	+50	
			V <sub>EN</sub> = 0.5 V, M, D <u>2/</u>		1	-50	
	-I <sub>S(OFF)</sub>	V <sub>S</sub> = -10 V, V <sub>EN</sub> = 0.8 V, all unused inputs = +10 V, V <sub>D</sub> = +10 V	1	01, 02	-10	+10	
			2, 3		-50	+50	
			V <sub>EN</sub> = 0.5 V, M, D <u>2/</u>		1	-50	
Leakage current into the drain terminal of an "OFF" switch	+I <sub>D(OFF)</sub>	V <sub>D</sub> = +10 V, V <sub>EN</sub> = 0.8 V, all unused inputs = -10 V	1	01, 02	-10	+10	nA
			2, 3	01	-200	+200	
				02	-100	+100	
			V <sub>EN</sub> = 0.5 V, M, D <u>2/</u>	1	01	-200	
		02		-100	+100		
	-I <sub>D(OFF)</sub>	V <sub>D</sub> = -10 V, V <sub>EN</sub> = 0.8 V, all unused inputs = +10 V	1	01, 02	-10	+10	
			2, 3	01	-200	+200	
				02	-100	+100	
V <sub>EN</sub> = 0.5 V, M, D <u>2/</u>			1	01	-200	+200	
		02	-100	+100			

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued.

Test	Symbol	Conditions -55°C ≤ T <sub>A</sub> ≤ +125°C -V = -15 V, +V = +15 V  V <sub>EN</sub> = 4.0 V unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Leakage current from an “ON” driver into the switch (drain)	+I <sub>D(ON)</sub>	V <sub>D</sub> = +10 V, V <sub>S</sub> = +10 V, all unused inputs = -10 V	1	01, 02	-10	+10	nA
			2, 3	01	-200	+200	
				02	-100	+100	
		V <sub>EN</sub> = 4.5 V, M, D <u>2/</u>	1	01	-200	+200	
				02	-100	+100	
		-I <sub>D(ON)</sub>	V <sub>D</sub> = -10 V, V <sub>S</sub> = -10 V, all unused inputs = +10 V	1	01, 02	-10	
2, 3	01			-200	+200		
			02	-100	+100		
V <sub>EN</sub> = 4.5 V, M, D <u>2/</u>	1		01	-200	+200		
			02	-100	+100		
Overvoltage protected, leakage current into the drain terminal of an “ON” switch	+I <sub>D(OFF)</sub> Over- voltage		V <sub>S</sub> = 33 V, V <sub>D</sub> = 0 V, V <sub>EN</sub> = 0.8 V	1, 2, 3	01, 02	-2.0	+2.0
		V <sub>EN</sub> = 0.5 V, M, D <u>2/</u>		1		-5.0	+5.0
	-I <sub>D(OFF)</sub> Over- voltage	V <sub>S</sub> = -33 V, V <sub>D</sub> = 0 V, V <sub>EN</sub> = 0.8 V	1, 2, 3	01, 02	-2.0	+2.0	μA
			V <sub>EN</sub> = 0.5 V, M, D <u>2/</u>		1	-5.0	
Positive supply current	+I	V <sub>A</sub> = 0 V, V <sub>EN</sub> = 4.0 V	1, 2, 3	01, 02		2.0	mA
			V <sub>EN</sub> = 4.5 V, M, D <u>2/</u>		1		
Negative supply current	-I	V <sub>A</sub> = 0 V, V <sub>EN</sub> = 4.0 V	1, 2, 3	01, 02		-1.0	mA
			V <sub>EN</sub> = 4.5 V, M, D <u>2/</u>		1		
Standby positive supply current	+I <sub>SBY</sub>	V <sub>A</sub> = 0 V, V <sub>EN</sub> = 0 V	1, 2, 3	01, 02		2.0	mA
			M, D <u>2/</u>		1		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued.

Test	Symbol	Conditions -55°C ≤ T <sub>A</sub> ≤ +125°C -V = -15 V, +V = +15 V  V <sub>EN</sub> = 4.0 V unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Standby negative supply current	-I <sub>SBY</sub>	V <sub>A</sub> = 0 V, V <sub>EN</sub> = 0 V  M, D 2/	1, 2, 3	01, 02		-1.0	mA
			1			-1.0	
Switch “ON” resistance	+R <sub>DS1</sub>	V <sub>S</sub> = 10 V, I <sub>D</sub> = -100 μA  V <sub>EN</sub> = 4.5 V, M, D 2/	1	01, 02		1500	Ω
			2, 3			1800	
			1			1800	
	-R <sub>DS1</sub>	V <sub>S</sub> = -10 V, I <sub>D</sub> = +100 μA  V <sub>EN</sub> = 4.5 V, M, D 2/	1	01, 02		1500	Ω
			2, 3			1800	
			1			1800	
Difference in switch “ON” resistance  between channels	+ΔR <sub>DS1</sub>	((+R <sub>DS1</sub> MAX)-(+R <sub>DS1</sub> MIN)x100) / R <sub>DS1</sub> AVE  V <sub>EN</sub> = 4.5 V, M, D 2/	1	01, 02		7	%
			1			7	
	-ΔR <sub>DS1</sub>	((-R <sub>DS1</sub> MAX)-(-R <sub>DS1</sub> MIN)x100) / -R <sub>DS1</sub> AVE  V <sub>EN</sub> = 4.5 V, M, D 2/	1	01, 02		7	%
			1			7	
Logic level voltage	V <sub>AL</sub>	3/, 4/  M, D 2/	1, 2, 3	01, 02		0.8	V
			1			0.5	
	V <sub>AH</sub>	3/, 4/  M, D 2/	1, 2, 3	01, 02	4.0		V
			1		4.5		
Capacitance: Address	C <sub>A</sub>	V <sub>+</sub> = V <sub>-</sub> = 0 V, f = 1 MHz, 5/ T <sub>A</sub> = +25°C, see 4.4.1d	4	01, 02		10	pF
Capacitance: Output switch	C <sub>OS</sub>	V <sub>+</sub> = V <sub>-</sub> = 0 V, f = 1 MHz, 5/ T <sub>A</sub> = +25°C, see 4.4.1d	4	01		45	pF
				02		25	
Capacitance: Input switch	C <sub>IS</sub>	V <sub>+</sub> = V <sub>-</sub> = 0 V, f = 1 MHz, 5/ T <sub>A</sub> = +25°C, see 4.4.1d	4	01, 02		15	pF
Charge transfer error	V <sub>CTE</sub>	V <sub>S</sub> = GND, f = 200 kHz, 5/ V <sub>GEN</sub> = 0 V to 5 V, T <sub>A</sub> = +25°C	4	01, 02		10	mV

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued.

Test	Symbol	Conditions -55°C ≤ T <sub>A</sub> ≤ +125°C -V = -15 V, +V = +15 V  V <sub>EN</sub> = 4.0 V unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Off isolation	V <sub>ISO</sub>	V <sub>EN</sub> = 0.8 V, R <sub>L</sub> = 1 kΩ, <sup>5/</sup> C <sub>L</sub> = 15 pF, V <sub>S</sub> = 7 V rms, f = 100 kHz, T <sub>A</sub> = +25°C	4	01, 02	-50		dB
Functional test	FT	See 4.4.1b	7, 8	01, 02			
Break-before-make time delay	t <sub>OPEN</sub>	See figure 3	9	01, 02	25		ns
			10, 11		5		
			M, D <sup>2/</sup>		5		
Propagation delay time: Address inputs  to I/O channels times	t <sub>A</sub>	See figure 3	9	01, 02		500	ns
			10, 11			1,000	
			M, D <sup>2/</sup>			1,000	
Enable to I/O	t <sub>ON(EN)</sub>	See figure 3	9	01, 02		500	ns
			10, 11			1,000	
			M, D <sup>2/</sup>			1,000	
	t <sub>OFF(EN)</sub>	See figure 3	9	01, 02		500	ns
			10, 11			1,000	
			M, D <sup>2/</sup>			1,000	

1/ Input current of one input mode.

2/ Devices supplied to this drawing meet all levels M and D of irradiation. However, these devices are only tested at D level. Pre and post irradiation values are identical unless otherwise specified in Table I.

3/ Used for forcing conditions for all DC tests, unless otherwise specified.

4/ To drive from DTL / TTL circuits, 1 kΩ pull-up resistors to +5.0 V supply are recommended.

5/ Guaranteed, if not tested, to the limits as specified.

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Case outline	E	
Device types	01	02
Terminal number	Terminal symbol	
1	A0	A0
2	ENABLE	ENABLE
3	-V <sub>SUPPLY</sub>	-V <sub>SUPPLY</sub>
4	IN 1	IN 1A
5	IN 2	IN 2A
6	IN 3	IN 3A
7	IN 4	IN 4A
8	OUT	OUTA
9	IN 8	OUTB
10	IN 7	IN 4B
11	IN 6	IN 3B
12	IN 5	IN 2B
13	+V <sub>SUPPLY</sub>	IN 1B
14	GND	+V <sub>SUPPLY</sub>
15	A2	GND
16	A1	A1

FIGURE 1. Terminal connections.

Device type 01

A2	A1	A0	EN	"ON" CHANNEL
X	X	X	L	NONE
L	L	L	H	1
L	L	H	H	2
L	H	L	H	3
L	H	H	H	4
H	L	L	H	5
H	L	H	H	6
H	H	L	H	7
H	H	H	H	8

Device type 02

A1	A0	EN	"ON" CHANNEL PAIR
X	X	L	NONE
L	L	H	1
L	H	H	2
H	L	H	3
H	H	H	4

FIGURE 2. Truth tables.

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BREAK-BEFORE-MAKE DELAY ( $t_{OPEN}$ )

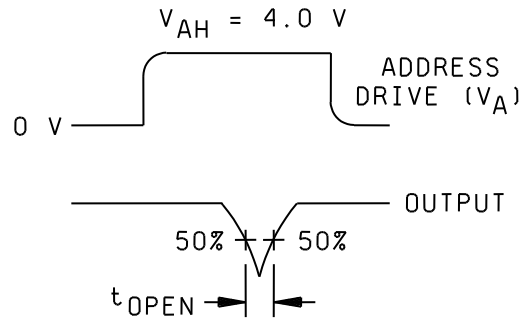
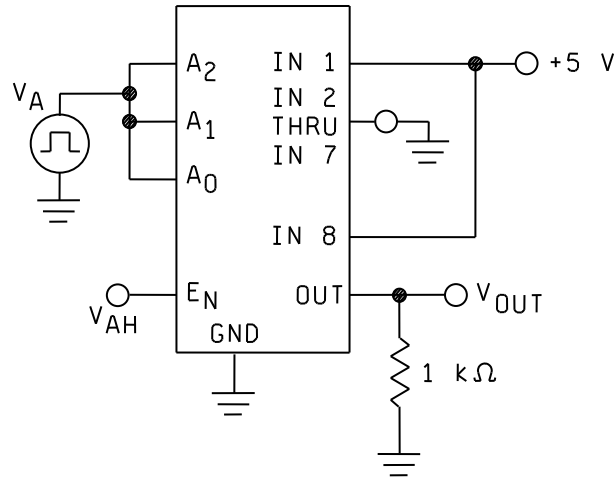


FIGURE 3. Timing diagrams.

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**E**

SHEET  
10

ACCESS TIME

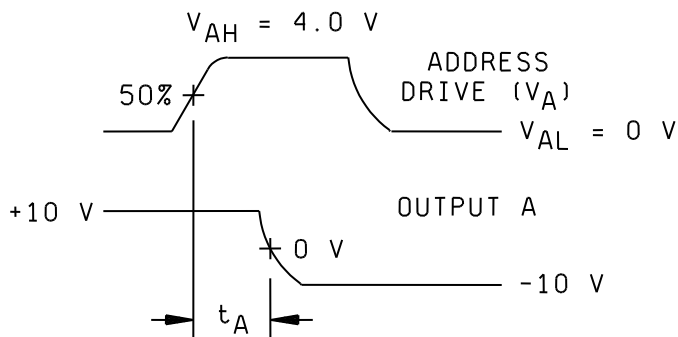
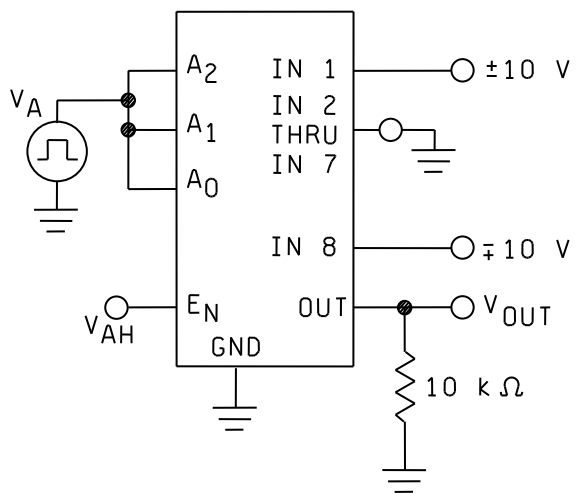


FIGURE 3. Timing diagrams - continued.

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SIZE  
**A**

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REVISION LEVEL  
E

SHEET  
11

ENABLE DELAY  
 $t_{ON(EN)}, t_{OFF(EN)}$

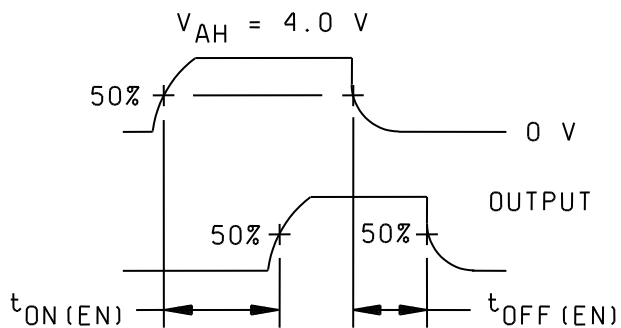
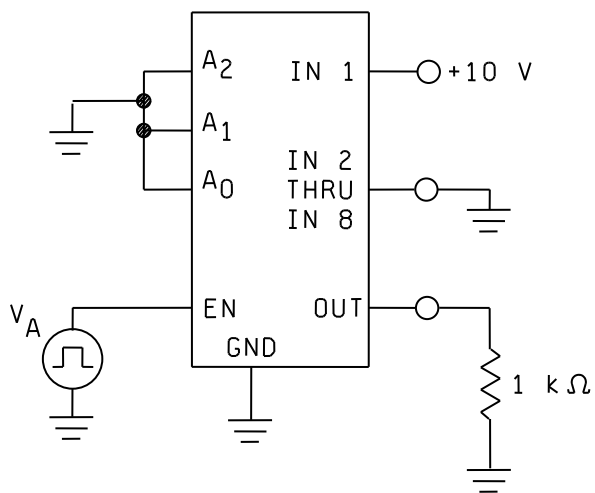


FIGURE 3. Timing diagrams - continued.

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SIZE  
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SHEET  
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4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections, and as specified herein.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.
- c. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- d. Subgroups 4 (C<sub>A</sub>, C<sub>IS</sub>, and C<sub>OS</sub> measurements) should be measured only for initial qualification and after any process or design changes which may affect input or output capacitance.

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TABLE IIA. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1, 7, 9	1, 7, 9
Final electrical parameters (see 4.2)	1, 2, 3, 7, 8, 9, 10, 11 <u>1/</u>	1, 2, 3, 7, 8, 9, 10, 11, $\Delta$ , <u>1/</u> , <u>2/</u>
Group A test requirements (see 4.4)	1, 2, 3, 4, 7, 8, 9, 10, 11 <u>3/</u>	1, 2, 3, 4, 7, 8, 9, 10, 11 <u>3/</u>
Group C end-point electrical parameters (see 4.4)	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3, 7, 8, 9, 10, 11, $\Delta$
Group D end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9
Group E end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9

1/ PDA applies to subgroup 1. For class V to subgroups 1 and  $\Delta$ .

2/ Delta limits (see table IIB) shall be required and the delta values shall be computed with reference to the zero hour electrical parameters (see table I).

3/ Subgroup 4, if not tested, shall be guaranteed to the limits specified in table I.

TABLE IIB. Burn-in delta parameters and group C delta parameters (+25°C).

Parameters	Symbol	Delta limits
Leakage current into the source terminal of an "OFF" switch	$I_{S(OFF)}$	$\pm 10$ nA
Leakage current into the drain terminal of an "OFF" switch	$I_{D(OFF)}$	$\pm 10$ nA
Leakage current from an "ON" driver into the switch (drain and source)	$I_{D(ON)}$	$\pm 10$ nA
Switch on resistance	$R_{DS}$	$\pm 150$ $\Omega$
Positive supply current	$I_+$	$\pm 200$ $\mu$ A
Negative supply current	$I_-$	$\pm 100$ $\mu$ A
Positive standby supply current	$+I_{SBY}$	$\pm 200$ $\mu$ A
Negative standby supply current	$-I_{SBY}$	$\pm 100$ $\mu$ A
Input leakage current	$I_{IL}, I_{IH}$	$\pm 100$ $\mu$ A

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.2.1 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

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4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

- a. End-point electrical parameters shall be as specified in table IIA herein.
- b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at  $T_A = +25^{\circ}\text{C} \pm 5^{\circ}\text{C}$ , after exposure, to the subgroups specified in table IIA herein.

4.4.4.1 Total dose irradiation testing. Total dose irradiation testing shall be performed in accordance with MIL-STD-883 method 1019 condition A and as specified herein.

4.4.4.1.1 Accelerated annealing test. Accelerated annealing tests shall be performed on all devices requiring a RHA level greater than 5k rads(Si). The post-anneal end-point electrical parameter limits shall be as specified in table I herein and shall be the pre-irradiation end-point electrical parameter limit at  $25^{\circ}\text{C} \pm 5^{\circ}\text{C}$ . Testing shall be performed at initial qualification and after any design or process changes which may affect the RHA response of the device.

4.4.4.2 Dose rate burnout. When required by the customer, test shall be performed on devices, SEC, or approved test structures at technology qualifications and after any design or process changes which may effect the RHA capability of the process. Dose rate burnout shall be performed in accordance with test method 1023 of MIL-STD-883 and as specified herein.

## 5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V.

## 6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime-VA, telephone (614) 692-8108.

6.4 Comments. Comments on this drawing should be directed to DLA Land and Maritime-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in MIL-HDBK-103 and QML-38535. The vendors listed in MIL-HDBK-103 and QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DLA Land and Maritime-VA and have agreed to this drawing.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 17-09-07

Approved sources of supply for SMD 5962-95694 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at <https://landandmaritimeapps.dla.mil/programs/smcr/>.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>
5962D9569401VEA	<u>3/</u>	HS1-0548RH-Q
5962D9569401VEC	34371	HS1B-0548RH-Q
5962D9569402VEA	<u>3/</u>	HS1-0549RH-Q
5962D9569402VEC	<u>3/</u>	HS1B-0549RH-Q

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply.

Vendor CAGE number

34371

Vendor name and address

Intersil Corporation  
1650 Robert J. Conlan Blvd. NE  
Palm Bay, FL 32905-3406

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.